650V/ 50A Silicon Carbide Power Schottky Barrier Diode

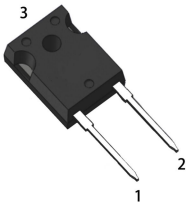
Features

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

Key Characteristics		
V_{RRM}	650	V
I_F, $T_c \leqslant 136℃$	50	A
Q_C	168	nC

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements



Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

Part No.	Package Type	Marking
G3S06550PM	TO-247AC	G3S06550PM

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		650	V
Surge Peak Reverse Voltage	V_{RSM}		650	V
DC Blocking Voltage	V_{DC}		650	V
Continuous Forward Current	I_F	T_C=25℃ T_C=125℃ T_C=136℃	130 68 50	A
Repetitive Peak Forward Surge Current	I_{FRM}	T_C=25℃, tp=10ms， Half Sine Wave，D=0.3	250	A
Non-repetitive Peak Forward Surge Current	I_{FSM}	T_C=25℃, tp=10ms， Half Sine Wave	400	A
Power Dissipation	P_{TOT}	T_C=25℃	454	W
		T_C=110℃	197	W
Operating Junction	T_j		-55℃ to 175℃	℃
Storage Temperature	T_{stg}		-55℃ to 175℃	℃
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in

Thermal Characteristics

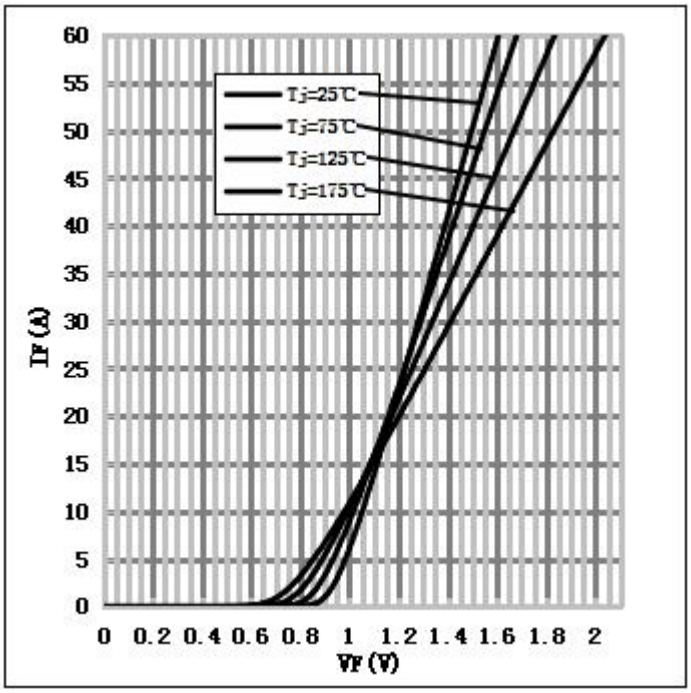
Parameter	Symbol	Test Condition	Value	Unit
			Typ.	
Thermal resistance from junction to case	$R_{th\ JC}$		0.33	℃/W

Electrical Characteristics

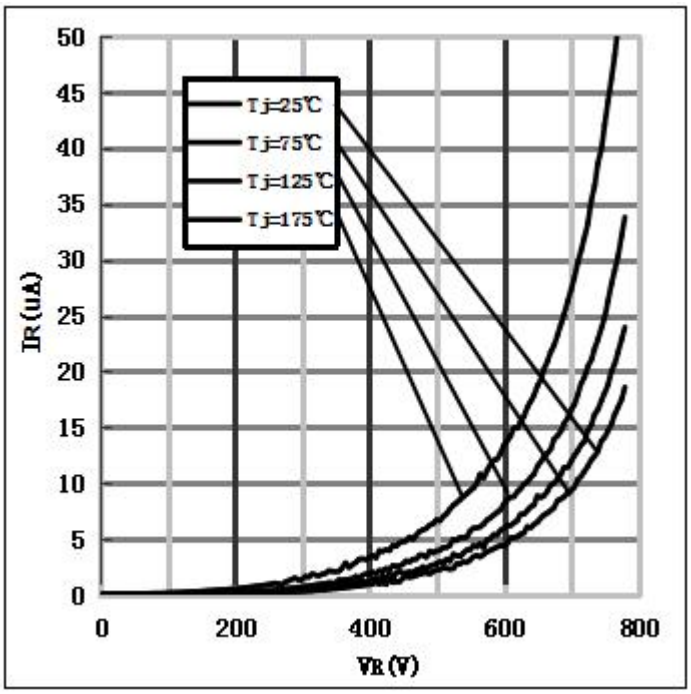
Parameter	Symbol	Test Conditions	Numerical		Unit
			Typ.	Max.	
Forward Voltage	V_F	I_F=50A, T_j=25℃	1.45	1.7	V
		I_F=50A, T_j=175℃	1.82	2.5	
Reverse Current	I_R	V_R=650V, T_j=25℃	6	50	μA
		V_R=650V, T_j=175℃	15	200	
Total Capacitive Charge	Q_C	V_R=400V, T_j=150℃ $Qc = \int_0^{VR} C(V)dV$	168	-	nC
Total Capacitance	C	V_R=0V, T_j=25℃, f=1MHZ	4400	4500	pF
		V_R=200V, T_j=25℃, f=1MHZ	306	320	
		V_R=400V, T_j=25℃, f=1MHZ	303	310	

Performance Graphs

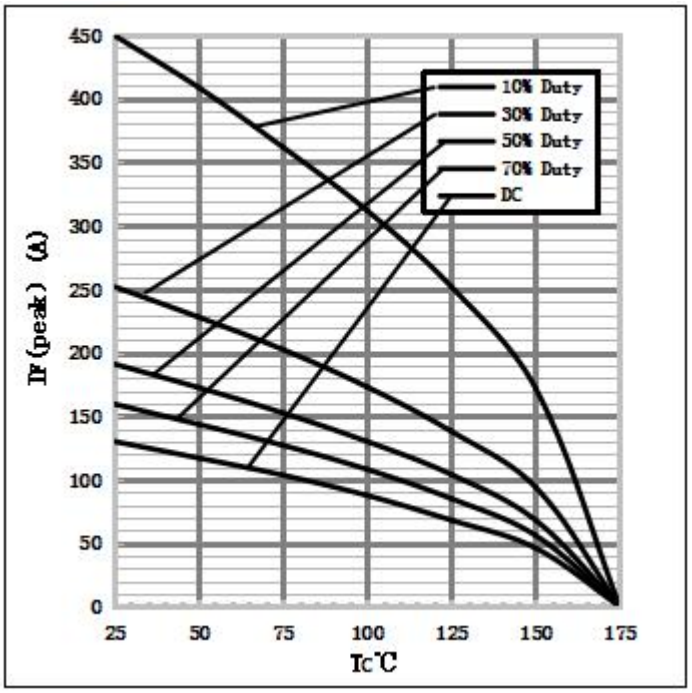
1) Forward IV characteristics as a function of Tj :



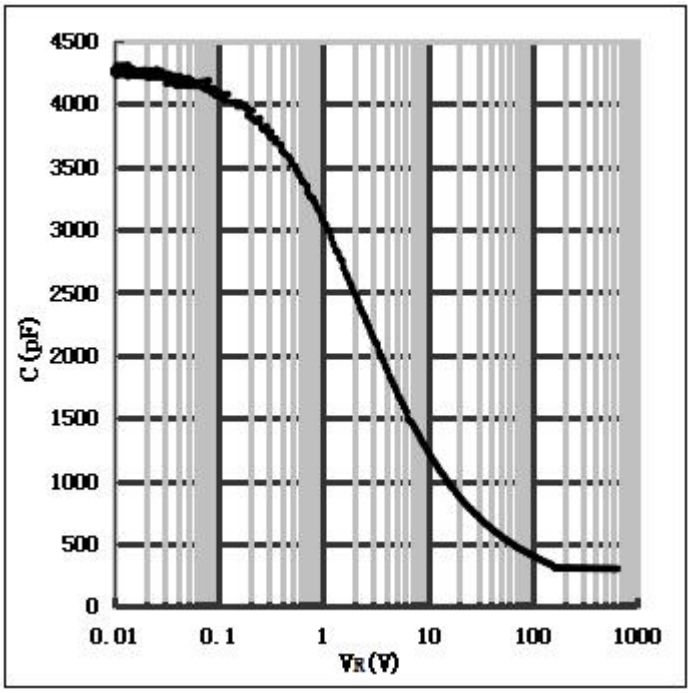
2) Reverse IV characteristics as a function of Tj :



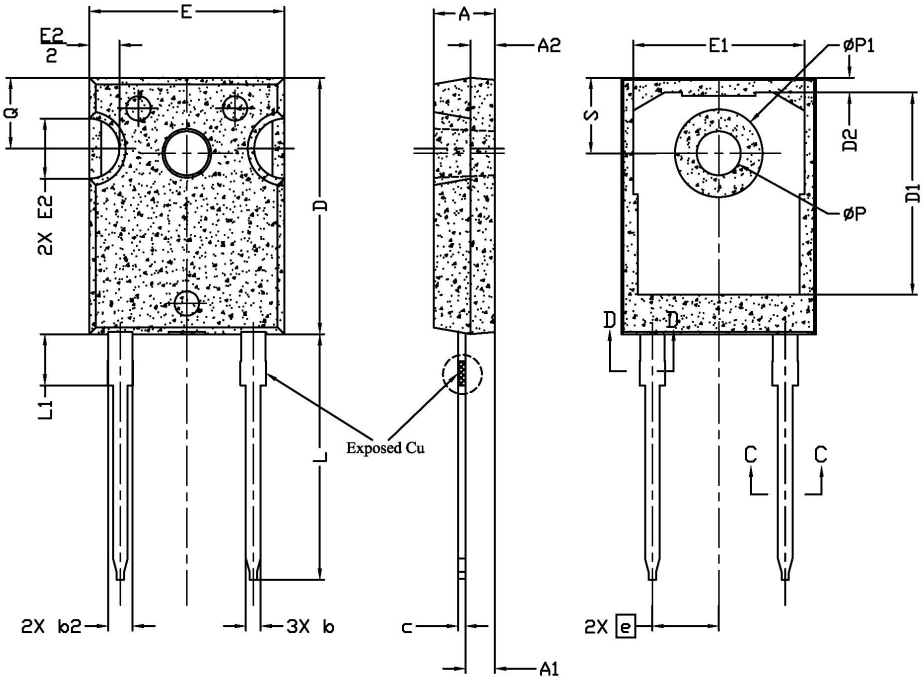
3) Current Derating:

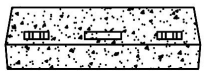


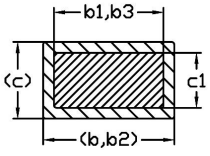
4) Capacitance vs. reverse voltage:



Package TO-247AC







Section C--C,D--D

Note:
1. Package Reference: JEDEC TO247, Variation AD.
2. All Dimensions Are In mm.
3. Slot Required, Notch May Be Rounded
4. Dimension D & E Do Not Include Mold Flash. Mold Flash Shall Not Exceed 0.127mm Pre Side. These Dimensions Are Measured At The Outermost Extreme Of The Plastic Body.
5. Thermal Pad Contour Optional Within Dimension D1 & E1.
6. Lead Finish Uncontrolled In L1.
7. ØP To Have A Maximum Draft Angle Of 1.5° To The Top Of The Part With A Maximum Hole Diameter Of 3.91mm.
8. Dimension "b2" And "b4" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.10mm Total In Excess Of "b2" And "b4" Dimension At Maximum Material Condition.

单位：mm

SYMBOL	DIMENSIONS			NOTES
	MIN.	NOM.	MAX.	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
b	1.12	1.20	1.33	
b1	1.12	1.20	1.28	
b2	1.91	2.00	2.39	6
b3	1.91	2.00	2.34	
c	0.55	0.60	0.69	6
c1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	7.19REF.			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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